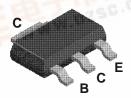


# NZT660 / NZT660A



**SOT-223** 

### **PNP Low Saturation Transistor**

These devices are designed with high current gain and low saturation voltage with collector currents up to 3A continuous.

**Absolute Maximum Ratings\*** T<sub>A = 25°C</sub> unless otherwise noted

|                                   |  | E 137 119      | 0.00  |
|-----------------------------------|--|----------------|-------|
| Symbol                            | Parameter  | NZT660/NZT660A | Units |
| V <sub>CEO</sub>                  | Collector-Emitter Voltage                        | 60             | V     |
| V <sub>CBO</sub>                  | Collector-Base Voltage                           | 80             | V     |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 5              | V     |
| Ic                                | Collector Current - Continuous                   | 3              | А     |
| T <sub>J</sub> , T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150    | °C    |

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- 1) These ratings are based on a maximum junction temperature of 150°C.
- WWW.DZSC.GOM 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

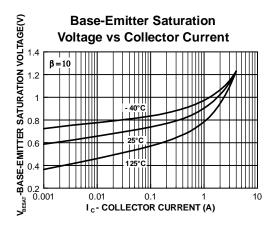
## Thermal Characteristics T<sub>A = 25°C unless otherwise noted</sub>

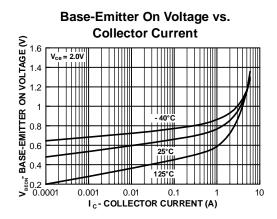
| Symbol          | Characteristic                          | Max            |      |  |
|-----------------|---|----------------|------|--|
| 192 14          | 7 1-4                                   | NZT660/NZT660A |      |  |
| P <sub>D</sub>  | Total Device Dissipation                | 2              | W    |  |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 62.5           | °C/W |  |

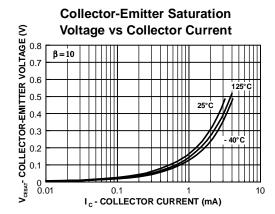
| PNP Lov<br>(continued)  | w Saturation Transistor              |  |          |      |       |  |  |  |  |
|---|--------------------------------------|--|----------|------|-------|--|--|--|--|
| Electrical Characteristics T <sub>A = 25°C unless otherwise noted</sub> |                                      |  |          |      |       |  |  |  |  |
| Symbol  | Parameter                            | Test Conditions  | Min      | Max  | Units |  |  |  |  |
| OFF CHA   | RACTERISTICS                         |  |          |      |       |  |  |  |  |
| BV <sub>CEO</sub>   | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> = 10 mA   | 60       |      | V     |  |  |  |  |
| BV <sub>CBO</sub>   | Collector-Base Breakdown Voltage     | I <sub>C</sub> = 100 μA  | 80       |      | V     |  |  |  |  |
| BV <sub>EBO</sub>   | Emitter-Base Breakdown Voltage       | I <sub>E</sub> = 100 μA  | 5        |      | V     |  |  |  |  |
| I <sub>CBO</sub>  | Collector Cutoff Current             | V <sub>CB</sub> = 30 V   |          | 100  | nA    |  |  |  |  |
|   |                                      | $V_{CB} = 30 \text{ V}, T_A = 100^{\circ}\text{C}$                                     |          | 10   | uA    |  |  |  |  |
| I <sub>EBO</sub>  | Emitter Cutoff Current               | V <sub>EB</sub> = 4V   |          | 100  | nA    |  |  |  |  |
| ON CHAR   | ACTERISTICS*                         |  |          | •    | 1     |  |  |  |  |
| h <sub>FE</sub>   | DC Current Gain                      | I <sub>C</sub> = 100 mA, V <sub>CE</sub> = 2 V   | 70       |      | -     |  |  |  |  |
|   |                                      | I <sub>C</sub> = 500 mA, V <sub>CE</sub> = 2 V <b>NZT660</b>                           | 100      | 300  |       |  |  |  |  |
|   |                                      | <b>NZT660A</b> I <sub>C</sub> = 1 A, V <sub>CE</sub> = 2 V                             | 250      | 550  |       |  |  |  |  |
|   |                                      | $I_C = 3 \text{ A}, V_{CE} = 2 \text{ V}$<br>$I_C = 3 \text{ A}, V_{CE} = 2 \text{ V}$ | 80<br>25 |      |       |  |  |  |  |
| V <sub>CE(sat)</sub>  | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA  |          | 300  | mV    |  |  |  |  |
| · OL(Sat)   |                                      | I <sub>C</sub> = 3 A, I <sub>B</sub> = 300 mA <b>NZT660</b>                            |          | 550  |       |  |  |  |  |
|   |                                      | NZT660A  |          | 500  |       |  |  |  |  |
| V <sub>BE(sat)</sub>  | Base-Emitter Saturation Voltage      | I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA  |          | 1.25 | V     |  |  |  |  |
| V <sub>BE(on)</sub>   | Base-Emitter On Voltage              | I <sub>C</sub> = 1 A, V <sub>CE</sub> = 2 V  |          | 1    | V     |  |  |  |  |
| SMALL SI  | GNAL CHARACTERISTICS                 |  |          |      |       |  |  |  |  |
| C <sub>obo</sub>  | Output Capacitance                   | V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1MHz                                   |          | 45   | pF    |  |  |  |  |
| f <sub>T</sub>  | Transition Frequency                 | I <sub>C</sub> = 100 mA,V <sub>CE</sub> = 5 V, f=100MHz                                | 75       |      | -     |  |  |  |  |

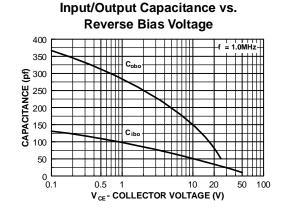
\*Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

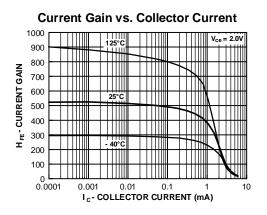
# **Typical Characteristics**

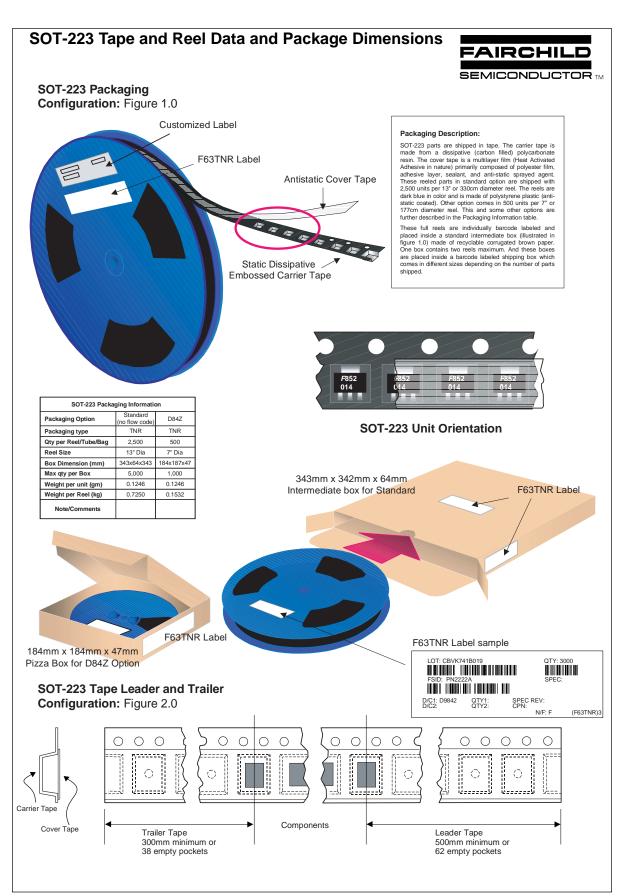






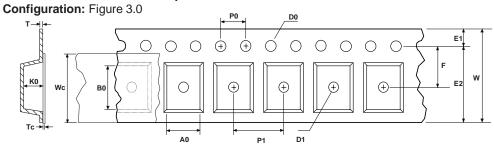






# SOT-223 Tape and Reel Data and Package Dimensions, continued

### **SOT-223 Embossed Carrier Tape**



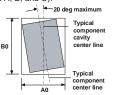
| User Direction of Feed |               |
|------------------------|---------------|
|                        | $\overline{}$ |

|                       | Dimensions are in millimeter |                 |                |                 |                 |                 |              |                 |               |               |                 |                        |                 |                 |
|-----------------------|------------------------------|-----------------|----------------|-----------------|-----------------|-----------------|--------------|-----------------|---------------|---------------|-----------------|------------------------|-----------------|-----------------|
| Pkg type              | Α0                           | В0              | w              | D0              | D1              | E1              | E2           | F               | P1            | P0            | K0              | т                      | Wc              | Тс              |
| <b>SOT-223</b> (12mm) | 6.83<br>+/-0.10              | 7.42<br>+/-0.10 | 12.0<br>+/-0.3 | 1.55<br>+/-0.05 | 1.50<br>+/-0.10 | 1.75<br>+/-0.10 | 10.25<br>min | 5.50<br>+/-0.05 | 8.0<br>+/-0.1 | 4.0<br>+/-0.1 | 1.88<br>+/-0.10 | 0.292<br>+/-<br>0.0130 | 9.5<br>+/-0.025 | 0.06<br>+/-0.02 |

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation

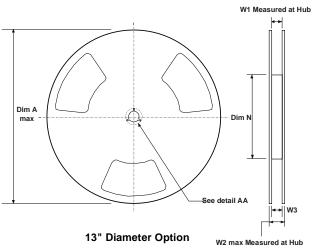


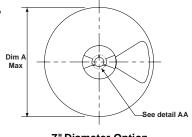
Sketch B (Top View)
Component Rotation



Sketch C (Top View)
Component lateral movement

### SOT-223 Reel Configuration: Figure 4.0



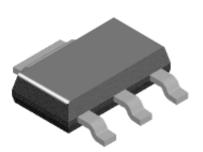


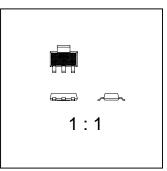
# 7" Diameter Option B Min Dim C DIM D DIM C

| Dimensions are in inches and millimeters |                |               |              |                                   |               |              |                                  |               |                              |
|--|----------------|---------------|--------------|-----------------------------------|---------------|--------------|----------------------------------|---------------|------------------------------|
| Tape Size                                | Reel<br>Option | Dim A         | Dim B        | Dim C                             | Dim D         | Dim N        | Dim W1                           | Dim W2        | Dim W3 (LSL-USL)             |
| 12mm                                     | 7" Dia         | 7.00<br>177.8 | 0.059<br>1.5 | 512 +0.020/-0.008<br>13 +0.5/-0.2 | 0.795<br>20.2 | 5.906<br>150 | 0.488 +0.078/-0.000<br>12.4 +2/0 | 0.724<br>18.4 | 0.469 - 0.606<br>11.9 - 15.4 |
| 12mm                                     | 13" Dia        | 13.00<br>330  | 0.059<br>1.5 | 512 +0.020/-0.008<br>13 +0.5/-0.2 | 0.795<br>20.2 | 7.00<br>178  | 0.488 +0.078/-0.000<br>12.4 +2/0 | 0.724<br>18.4 | 0.469 - 0.606<br>11.9 - 15.4 |

# SOT-223 Tape and Reel Data and Package Dimensions, continued

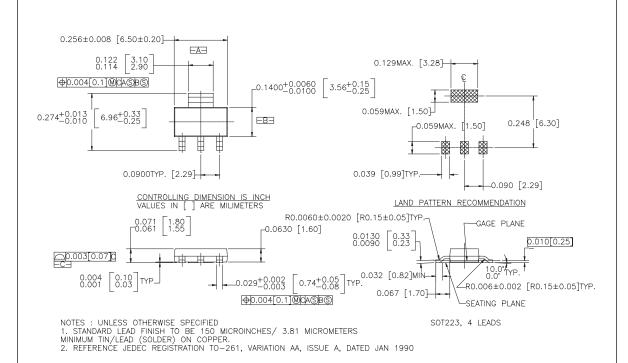
# SOT-223 (FS PKG Code 47)





Scale 1:1 on letter size paper

Part Weight per unit (gram): 0.1246



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